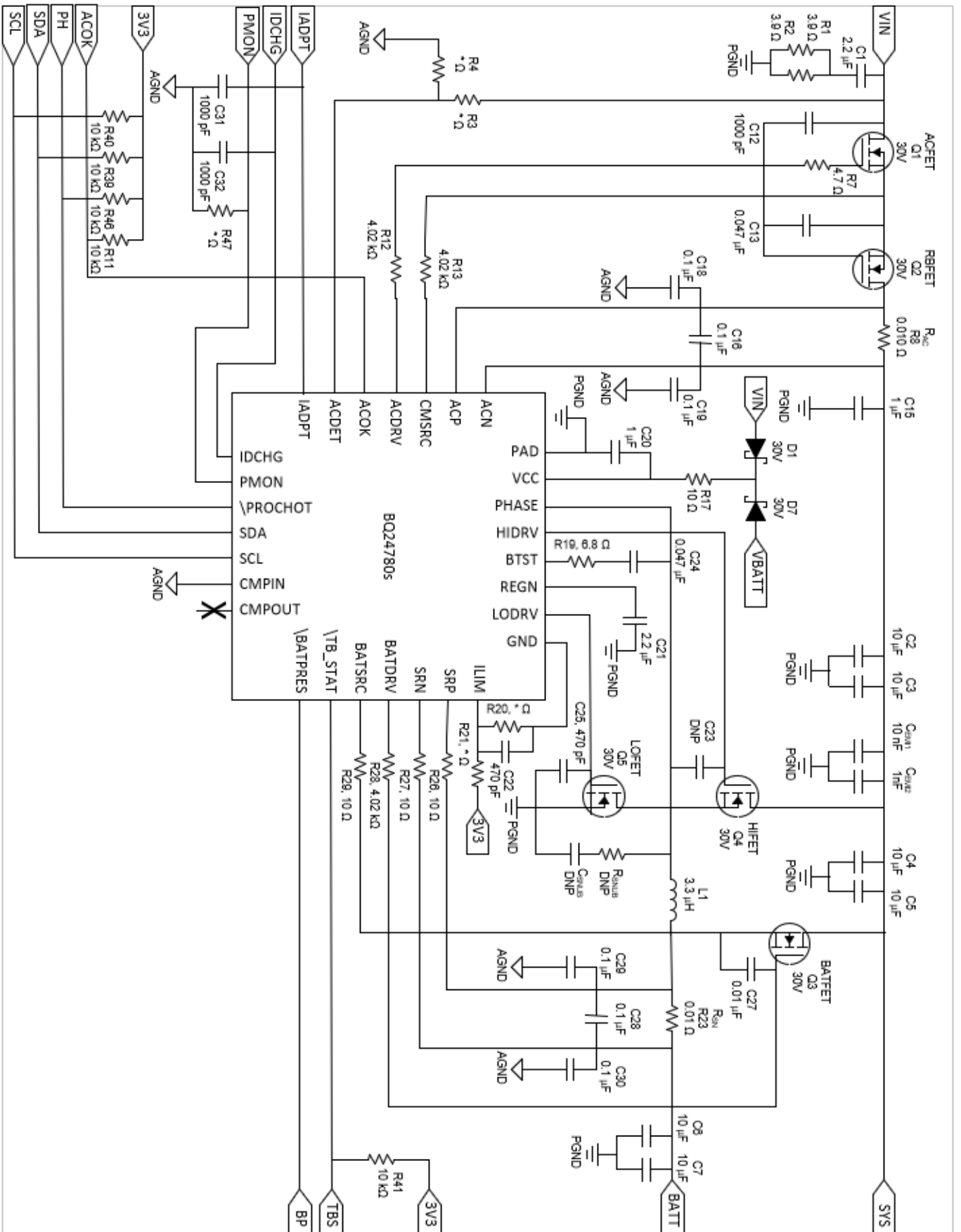
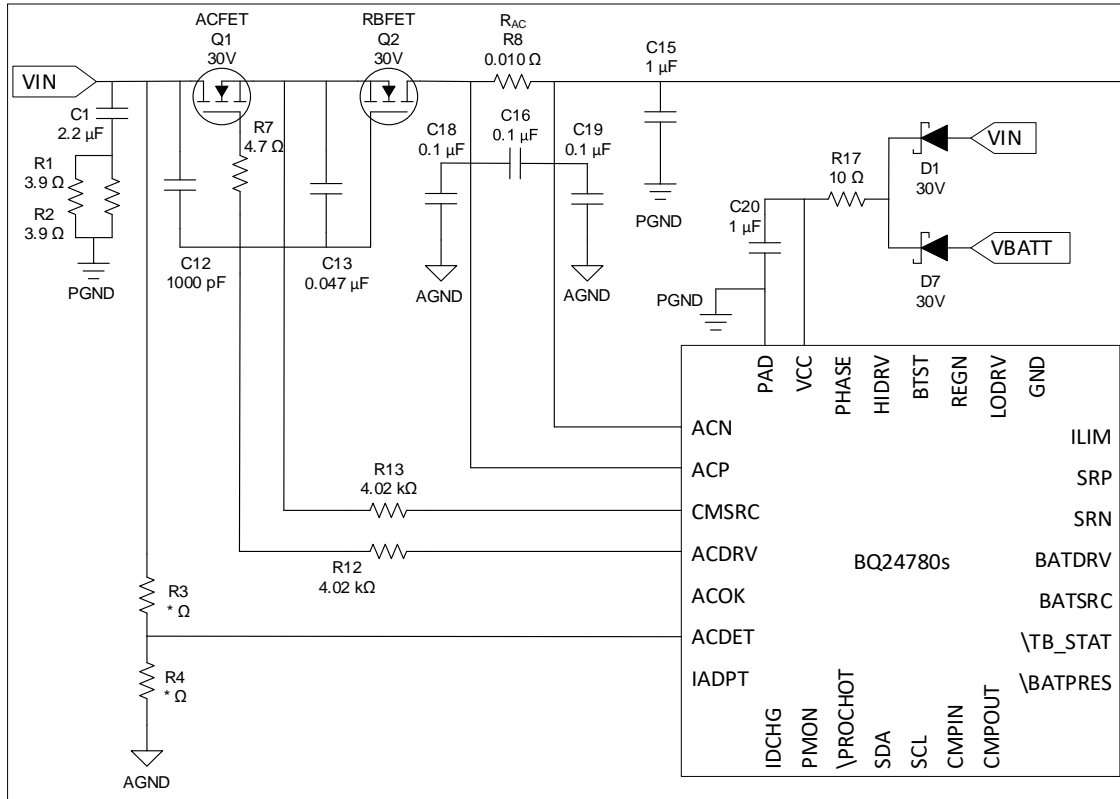


BQ24780s TYPICAL SCHEMATIC

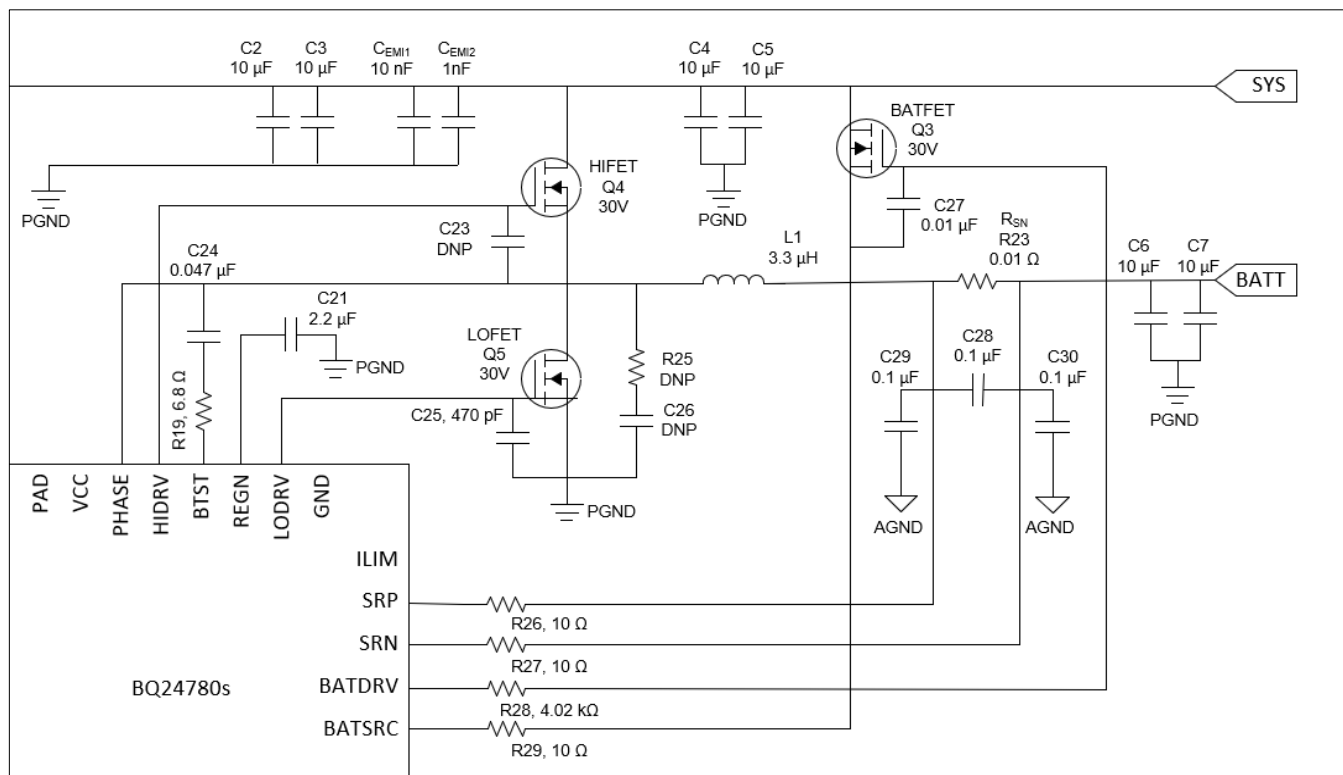


BQ24780s - Input Power Design



INPUT POWER - DESIGN CHECKLIST							
PIN NAME	REQUIREMENT	COMPONENT	MIN	TYP	MAX	DESCRIPTION	COMMENTS AND RELEVANT EQUATIONS
						Input source to the charger	
	Required	Q1		-		Back-to-back input protection N-Channel MOSFETs	Used to isolate the battery and adapter. This blocks reverse current from the battery back to the input and prevents short from adapter into battery.
	Required	R12		4.02 kΩ		Current-limiting resistors	
	Required	R13		4.02 kΩ			
	Recommended	R1/R2		2 Ω		Input hot-plug snubber circuit	
	Recommended	C1		2.2 μF		Input MOSFETs turn-on/turn-off delay	Used to dampen the ringing due to input inrush current
	Recommended	R7		4.7 Ω			
	Recommended	C12		1000 pF			
	Recommended	C13		0.047 μF			
						Differential input current sensing	
ACP-ACN	Required	R9 (R _{AC})		10 mΩ		Input current sensing resistor	
	Recommended	C15		1 μF		Switching noise filtering	
	Recommended	C16		0.1 μF		Differential mode noise filtering	
	Recommended	C18		0.1 μF		Common mode noise filtering	
	Recommended	C19		0.1 μF			
						AC Detect Resistor-Divider	
ACDET	Required	R3		* kΩ		High side of resistor-divider for adapter detection threshold	$V_{th} = 2.4V \frac{R_3 + R_4}{R_3} \quad R_3 + R_4 \approx 1 M\Omega$
	Required	R4		* kΩ		Low side of resistor-divider for adapter detection threshold	
						IC power positive supply	
VCC	Required	R17		10 Ω		VCC inrush current limiting	
	Required	C20		1.0 μF		VCC decoupling capacitor	
	Required	D1		-		Adapter/Battery Diode-OR	
	Required	D7		-		Adapter/Battery Diode-OR	

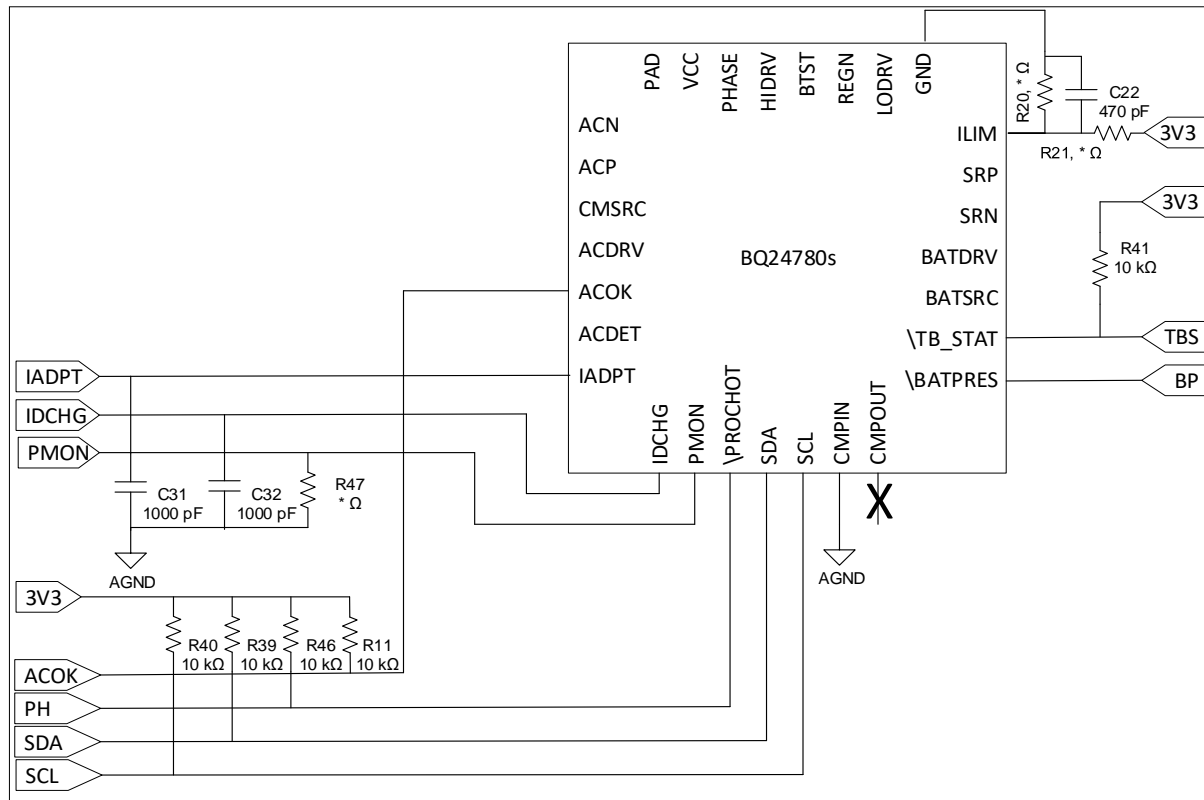
BQ24780s - Output Power Design



OUTPUT POWER - DESIGN CHECKLIST							
PIN NAME	REQUIREMENT	COMPONENT	MIN	TYP	MAX	DESCRIPTION	COMMENTS AND RELEVANT EQUATIONS
						System output	
	Required	C2/C3		20 uF		High frequency converter input capacitor(s)	
	Required	C4/C5		20 uF		Power path noise filtering capacitor(s)	
	Required	C10 on EVM		22 uF		System output noise filtering capacitor(s)	For more information please refer to EVM and "8.2.2.5 Input Capacitor" of the datasheet
						BATFET power path gate driver	
BATDRV	Required	Q3		-		External N-Channel BATFET for power path	
	Required	R28		4.02 kΩ		BATDRV current limiting resistor	
	Recommended	C27		0.01 uF		BATFET turn on/off delay capacitor	
						Switching Regulator Output Stage	
Switching Regulator Output Stage	Required	L1		*uH		Switching regulator inductor	Recommended: 10 kHz < fo < 20 kHz, typical L= 3.3 uH, C = 20 uF. Refer to "8.2.2.6 Output Capacitor" of the datasheet
	Required	C6/C7		*uF		Switching regulator output capacitor(s)	$f_o = \frac{1}{2 \cdot \pi \cdot \sqrt{L_{out} \cdot C_{out}}}$
						Differential charge current sensing	
SRP-SRN	Required	R23 (R _{SN})		10 mΩ		Charge current sensing resistor	
	Recommended	C28		0.1 uF		Differential mode noise filtering	
	Recommended	C29		0.1 uF		Common mode noise filtering	
	Recommended	C30		0.1 uF		Common mode noise filtering	
						Internal LDO output	
REGN	Required	C21		2.2 uF		Internal LDO output stabilizing capacitor	
						Low-Side N-Channel MOSFET driver	
LODRV	Recommended	C25		470 pF		Low-side FET timing capacitor	Slowing MOSFET turn-on/off reduces noise and EMI, but also reduces efficiency.
	Required	Q5		-		Converter Low-Side N-Channel MOSFET	
						PHASE & BTST	
PHASE & BTST	Required	C24		0.047 uF		Converter bootstrap capacitor	
	Recommended	R19		6.8 Ω		Bootstrap capacitor snubbing resistor	
	Optional	R25		* Ω		Switching converter snubber circuit	Snubber circuit values empirically determined if required. Recommend unpopulated footprint on new designs.
	Optional	C26		* uF		Switching converter snubber circuit	

HIDRV	26	Required	Q4	-	High-Side N-Channel MOSFET driver	
		Optional (DNP)	C23	* pF	Converter active High-Side N-Channel MOSFET	Slowing MOSFET turn-on/off reduces noise and EMI, but also reduces efficiency.
EMI Reduction	HIFET				EMI	
		Optional	CEM12	1 nF	HI-side FET EMI Filter Caps	
		Optional	CEM11	10 nF		

BQ24780s - Miscellaneous Components Design



Miscellaneous - DESIGN CHECKLIST								
PIN		REQUIREMENT	COMPONENT	MIN	TYP	MAX	DESCRIPTION	COMMENTS AND RELEVANT EQUATIONS
SDA/SCL	pin 11 and pin 12	Required	R39		10 kΩ		Pull-up resistors to 3.3V	
		Required	R40		10 kΩ			
ACOK	5	Required	R11		10 kΩ		ACOK pull-up resistor to 3.3V	
							Prochot Pullup	
\PROCHOT	10	Required	R46		10 kΩ		\PROCHOT pull-up resistor to 3.3V	
							Power Monitor	
PMON	9	Optional	R47		* Ω			
		Optional	C33 on EVM		0	100 pF		
IDCHG	8	Optional	C32		100 pF	100 pF	Discharge Current	
IADPT	7	Optional	C31		100 pF	100 pF	Adapter Current	
ILIM	21	Required	R20 on EVM		* Ω		ILIM Resistor divider	
		Required	R21 on EVM		* Ω			

Refer to "Pin Functions" section of datasheet

TB_STAT	16	Optional	R41		10 kΩ	Turbo Boost Status TB_STAT pull-up resistor to 3.3V
CMPIN/CMPOUT	13-14	Optional			-	Independent Comparator If unused, Ground CMPIN and float CMPOUT
GND & PAD	22 & PAD	Required	-		-	IC Ground return Recommend separate analog and power ground. GND pin 22 connects to analog ground, PAD connects to power ground. Join analog and power ground at single point with 0-ohm resistor, net tie or 10 mil trace